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SPIN-POLARIZED TRANSPORT AT THE NANOSCALE



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A BRIEF HISTORY

Magnetism is a very old science

• The first magnetic devices

Chinese South pointer (1080)



Portuguese Compass 15th century



• Connection between magnetism and electricity (19th century)





Oersted

Ampère

Faraday





22 A BRIEF HISTORY

Maxwell put it in equations



$$\nabla \cdot \boldsymbol{B} = 0,$$

$$\epsilon_0 \nabla \cdot \boldsymbol{E} = \rho,$$

$$(1/\mu_0) \nabla \times \boldsymbol{B} = \boldsymbol{j} + \epsilon_0 \partial \boldsymbol{E} / \partial t,$$

$$\nabla \times \boldsymbol{E} = -\partial \boldsymbol{B} / \partial t.$$

Magnetism and quantum mechanics

Intrinsic spin of the electron: Uhlenbeck Goudmsith 1925 Ferromagnetim: Heisenberg Antiferromagnetism: Néel



REVIVAL OF MAGNETISM

Magnetism is still a very active science & technology





Short Intro

Anisotropic Magneto Resistance in Nanocontacts

C60/Cr(001) molecule seen from a SP-STM tip

Conclusions and perspectives

ANISOTROPIC MAGNETO RESISTANCE IN NANOCONTACTS

WHAT IS AMR?

An OLD Story

Anisotropic Magneto Resistance of bulk Iron (Thomson 1857!)

•
$$\rho_{\parallel} \neq \rho_{\perp}$$
 $AMR = \frac{\rho_{\parallel} - \rho_{\perp}}{\rho_{av}}$

- AMR≈1%
- Origin: Spin-Orbit Coupling (1960)



Revisited by Nanophysics

AMR in atomic contacts (M. Viret 2006!)

- AMR≈20-30%
- Two-levels curve



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EXPERIMENTAL SET-UP

Break junction technique



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EXPERIMENTAL FACTS



EPJB **51**,1 (2006)

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Electronic and Magnetic structure

TB Hamiltonian in a minimal atomic-like basis set

Spin polarized calculation

Spin-orbit coupling

Magnetic anisotropy

ElectronicTransport

Green function formalism in a local basis set

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MAGNETIC TB MODEL



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TB₀: MEHL AND PAPACONSTANOPOULOS



PRB 54 ,	4519 (1996)
PRB 58 ,	9721 (1998)

$$E_{tot} = \sum_{\alpha} f_{\alpha} \mathcal{E}_{\alpha}$$



LOCAL CHARGE NEUTRALITY

$$H_{LCN}^{i\lambda,i\lambda} = U_i \Delta n_i = U_i (n_i - n_{i,0})$$

$$H_{LCN}^{i\lambda,j\mu} = \frac{1}{2} \Big[U_i (n_i - n_{i,0}) + U_j (n_j - n_{j,0}) \Big] S_{i\lambda,j\mu}$$

Avoid charge transfers between inequivalent atoms (very good for metals)





Fixed spin moment calculation

$$E_{tot} = \int_{-\infty}^{E_F^{\uparrow}} ED_{\downarrow}(E) dE + \int_{-\infty}^{E_F^{\downarrow}} ED_{\downarrow}(E) dE + \frac{1}{4} \operatorname{Im}^2 \qquad D_{\sigma}(E) = D_0(E + \frac{1}{2}\sigma IM)$$

E(m)

 $\bar{m_0}$

$$E_{tot}(M) = \int_{F_{F}}^{E_{F}} ED_{0}(E)dE + \int_{F_{F}}^{E_{F}} ED_{0}(E)dE - \frac{1}{4} \text{Im}^{2}$$

$$M = \int_{F_{F}}^{E_{F}} ED_{0}(E)dE - \int_{F_{F}}^{E_{F}} ED_{0}(E)dE \qquad E_{F}^{+} = E_{F}^{\uparrow} + \frac{1}{2} \text{Im}$$

$$N = \int_{F_{F}}^{E_{F}} ED_{0}(E)dE + \int_{F_{F}}^{E_{F}} ED_{0}(E)dE \qquad E_{F}^{-} = E_{F}^{\uparrow} - \frac{1}{2} \text{Im}$$

Penalization of local magnetization

$$E_{tot} = \sum_{\alpha occ} \sum_{i,j} c_i^{\alpha} c_j^{\alpha} H_{ij} + E_{pen}$$

 m_1

$$E_{\text{pen}} = \sum_{i} \lambda_{i} (m_{i} - m_{i,0})^{2}$$

$$E_{\text{pen}} = \sum_{i}^{i} \lambda_{i} (\cos \theta_{i} - \cos \theta_{i,0})^{2}$$

$$\operatorname{Min} E_{\operatorname{tot}} / \sum_{i} \left(c_{i}^{\alpha} \right)^{2} = 1 \Longrightarrow H = H_{0} + H_{\operatorname{pen}}$$

 m_i

BEYOND STONER MODEL= TB+U(J,B)

 $H = H_0 + H_{\text{int}}$

$$H_{\text{int}} = \frac{1}{2} \sum_{i\alpha_{1}\alpha_{2}\alpha_{3}\alpha_{4}} U_{i\alpha_{1}\alpha_{2}\alpha_{3}\alpha_{4}} c_{i\alpha_{1}\sigma}^{+} c_{i\alpha_{2}\sigma}^{+} c_{i\alpha_{4}\sigma}^{-} c_{i\alpha_{3}\sigma} \qquad \alpha_{n} = d(f) \text{ orbitals}$$

$$i: \text{ atomic site}$$
Hartree Fock decoupling (mean field)
$$H_{\text{mag}} = H_{\text{int}}^{HF} = \frac{1}{2} \sum_{i\alpha_{1}\alpha_{3}\alpha_{3}\alpha_{4}} \left(U_{i\alpha_{4}\alpha_{2}\alpha_{3}\alpha_{1}} \left\langle c_{i\alpha_{4}\sigma}^{+} c_{i\alpha_{3}\sigma} \right\rangle c_{i\alpha_{2}\sigma}^{+} c_{i\alpha_{1}\sigma}^{-} - U_{i\alpha_{4}\alpha_{2}\alpha_{1}\alpha_{3}} \left\langle c_{i\alpha_{4}\sigma}^{+} c_{i\alpha_{3}\sigma}^{-} \right\rangle c_{i\alpha_{2}\sigma}^{+} c_{i\alpha_{1}\sigma}^{-} \right)$$

$$U_{m_{1}m_{2}m_{3}m_{4}} = \int_{-\infty}^{+\infty} d^{3}r \int_{-\infty}^{+\infty} d^{3}r' \varphi_{im_{1}\sigma}^{*} (\vec{r}) \varphi_{im_{2}\sigma}^{*} (\vec{r}') \frac{e^{2}}{|\vec{r} - \vec{r}'|} \varphi_{im_{3}\sigma}^{-} (\vec{r}) \varphi_{im_{4}\sigma}^{-} (\vec{r}')$$

$$U_{\lambda_{1}\lambda_{2}\lambda_{3}\lambda_{4}} = \int_{-\infty}^{+\infty} d^{3}r \int_{-\infty}^{+\infty} d^{3}r' \varphi_{i\lambda_{1}\sigma}^{-} (\vec{r}) \varphi_{i\lambda_{2}\sigma}^{-} (\vec{r}') \frac{e^{2}}{|\vec{r} - \vec{r}'|} \varphi_{i\lambda_{3}\sigma}^{-} (\vec{r}) \varphi_{i\lambda_{4}\sigma}^{-} (\vec{r}')$$

$$U_{\alpha_{1}\alpha_{2}\alpha_{3}\alpha_{4}} = \text{linear combination}(A, B, C)$$
Racah parameters:
$$(F_{0}, F_{2}, F_{4})$$
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New set of parameters

real orbitals

$$U = \frac{1}{4} \sum_{\mu,\mu\neq\lambda} U_{\lambda\mu\lambda\mu} = A - B + C = F^0 - \frac{1}{49} (F^2 + F^4)$$
$$J = \frac{1}{4} \sum_{\mu,\mu\neq\lambda} U_{\lambda\mu\mu\lambda} = \frac{5}{2} B + C = \frac{5}{98} (F^2 + F^4)$$

spherical harmonics (Anisimov)

$$U_{A} = \frac{1}{25} \sum_{mm'} U_{mm'} = A + \frac{7}{5} C = F^{0} \qquad \qquad U_{A} - J_{A} = \frac{1}{20} \sum_{mm' \atop m \neq m'} (U_{mm'} - J_{mm'})$$

$$J_A = \frac{7}{2}B + \frac{7}{5}C = \frac{1}{14}(F^2 + F^4)$$

$$\begin{bmatrix} U_A = U + \frac{2J}{5} \\ J_A = \frac{7}{5}J \end{bmatrix} \iff \begin{bmatrix} U = U_A - \frac{2J_A}{7} \\ J = \frac{5}{7}J_A \end{bmatrix}$$

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 $(A, B, C) \implies (U, J, B)$

From HF to Stoner

$$n_{i,\lambda\sigma,\mu\sigma'} = \overline{n}_{i,\sigma} \delta_{\lambda\sigma,\mu\sigma'} \qquad \overline{n}_{i,\sigma} = \frac{1}{5} \sum_{\lambda} n_{i,\lambda,\sigma}$$

$$H_{\text{int}} \rightarrow H = \sum_{i\lambda\sigma} (U_{eff} n_{i\lambda\sigma} - \frac{1}{2} I_{dd} m_{i\lambda\sigma}) c^{\dagger}_{i\lambda\sigma} c_{i\lambda\sigma}$$

$$U_{eff} = (9U - 2J)/5 \qquad I_{dd} = (U + 6J)/5$$



Controls the spin-moment

U-J,B Controls the orbital-moment and anisotropy

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SPIN-ORBIT COUPLING

$$H_{\rm SOC} = \sum_{i} \xi_i(r) \vec{L}_i \cdot \vec{S}_i$$

We keep d orbitals only

$$\xi_{i,d} = \int R_{i,d}^2(r) r^2 dr$$







TB PARAMETERS



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TRANSPORT MODELLING







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SIMPLE ATTRACTIVE (BUT WRONG) MODEL OF AMR IN NANOCONTACTS

BAMR of a monatomic wire



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« REALITY » IS MUCH MORE COMPLEX

No wire in 3d elements



Role of contacts

Reflexion at interfaces

Magnetic coupling with electrodes



« Filtering » of δ -like electrons at the interface

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« REALISTIC » MODEL

Realistic atomic contact



Realistic electronic structure

non collinear magnetism + SOC + U(J,B)

$$H = H_0 + H_{LCN} + H_{mag} + H_{SO}$$

$$H_{mag} \begin{cases} H_{Stoner} \\ H_{HF} \end{cases}$$



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Right sign of AMR

Right sign of AMR

AMR~10%

Continuous AMR

AMR~30%

Two-level AMR

From BAMR to AAMR



SPIN-POLARIZED TRANSPORT THROUGH C60/CR(001)



SP-STM/STS EXPERIMENTS



Topographic mode

$$I(z(x, y), U = cte) = cte \Longrightarrow z(x, y)$$

Spectroscopic mode

$$G = \frac{dI}{dU}(U)$$
 $z(x, y)$ fixed

Topographic mode



Spectroscopic mode





TUNNEL CURRENT TERSOFF-HAMANN APPROXIMATION



$$I_t(U) \sim D_T \int_{E_F}^{E_F + eU} D_S(E, R_T) dE \qquad D_T(E) \sim cte$$
$$G = \frac{dI}{dU} \sim D_T D_S(E_F + eU, R_T)$$

$$D(E_F + eU, R_T) = \sum_{\alpha, k} \left| \Psi_{\alpha, k}(R_T) \right|^2 \delta(E_F + eU - \varepsilon_{\alpha}(k))$$

Spin-Polarized Tunnel Current

$$G = \frac{dI}{dU} \sim \sum_{\sigma} D_T^{\sigma} D_S^{\sigma} (E_F + eU, R_T)$$



Fully polarized tip

$$D_T^{\uparrow} = 0 \quad D_T^{\downarrow} \neq 0$$

(or vice-versa if the tip and the substrate have opposite polarization)

$$G \sim D_S^{\uparrow\downarrow}(E_F + eU, R_T)$$



ab initio electronic structure package Quantum-ESPRESSO

Main ingredients

- Density Functional Theory (DFT)
- plane waves basis set for wave functions;
- ultrasoft pseudo potentials to describe electron-ion interactions;





- 185 atoms, size 15Ax15Ax30A, FFT grid = (150,150,320);
- "running time" 30 h on 32 CPU

Atomic relaxation





Most stable position:

« on top » on a pentagonal ring
 « flatenning » of the molecule in contact with Cr

Small anecdote: Non magnetic C60/Cr(001) is unstable because Cr(001) « wants » to reconstruct Same as Mo(001) and W(001)

"isolated" C60 molecular spectrum



Degeneracy lifting due to the distorsion provoked by the interaction with the substrate

PDOS on molecular orbitals



Vacuum LDOS

$$D(E_F + eU, R_T) = \sum_{\alpha, k} \left| \Psi_{\alpha, k}(R_T) \right|^2 \delta(E_F + eU - \varepsilon_{\alpha}(k))$$





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TMR



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SP-STS+ topography



Topography I(z(x, y), U) = cte+ spectroscopy $G = \frac{dI}{dU}(U)$

$$I_t(U) \sim \int_{E_F}^{E_F + eU} D_S(E, R_T(x, y, z)) dE$$
$$G \sim D_S(E_F + eU, R_T(x, y, z))$$



CONCLUSIONS & PERSPECTIVES

nanocontacts

- Enhanced magnetoresistive effect
- Correlation & orbital polarization can be important
- 3 Take into account potential drop in the contact
- A Nanocontacts of alloys

Molecular spintronics

- Large TMR effects are possible
- Strong dependence on the atomic geometry
- 3 Can we control spin transport with an external parameter
- Output Can we optimize the system to enhance TMR?

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Spin polarizedTransport

Break junction experiment

SP-STM experiment

THANK YOU FOR YOUR ATTENTION

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